NSN 5961-01-131-6631

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-131-6631 **Inclosure Material:** Plastic **Overall Length:** 0.705 inches **Terminal Length:** 0.381 inches **Overall Height:** 0.546 inches **Overall Width:** 0.400 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 repetitive peak off-state voltage and 1.5 gate trigger voltage, dc **Current Rating Per Characteristic:** 25.00 amperes forward current, total rms nanoamperes and 300.00 amperes peak forward surge current nanoamperes and 75.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0